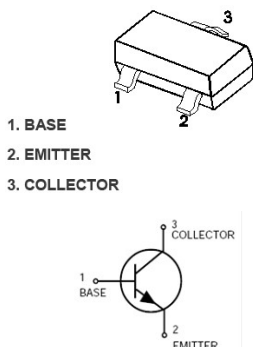


SOT-23

Marking: 1AM
特征 Features

- Power Dissipation of 200mW
- High Stability and High Reliability

机械数据 Mechanical Data

- SOT-23 Small Outline Plastic Package
- Epoxy UL: 94V-0
- Mounting Position: Any
- High temperature soldering guaranteed: 260°C/10s
- We declare that the material of product compliant with RoHS requirements and Halogen free

极限值和温度特性(TA = 25°C 除非另有规定)

Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

参数 Parameters	符号 Symbol	数值 Value	单位 Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter -Base Voltage	V _{EBO}	6	V
Collector Current-Continuous	I _C	200	mA
Collector Power Dissipation	P _C	200	mW
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55-+150	°C
Thermal resistance From junction to ambient	R _{θJA}	625	°C/W

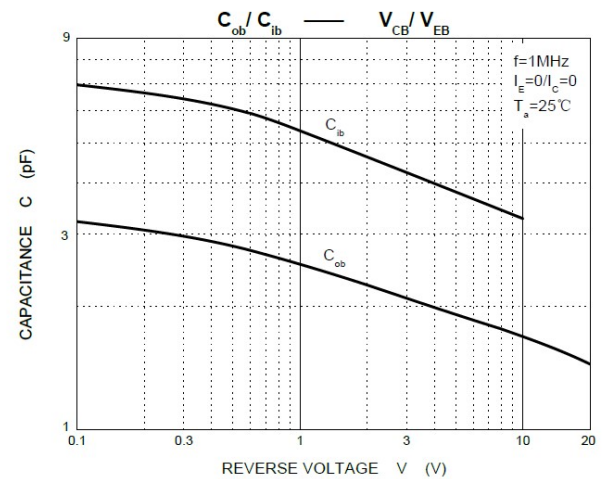
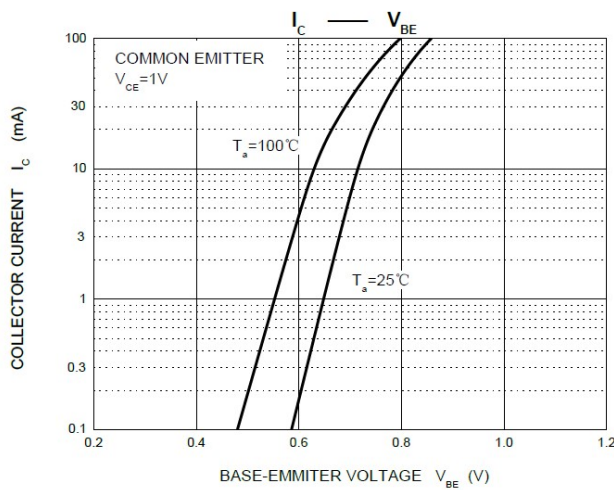
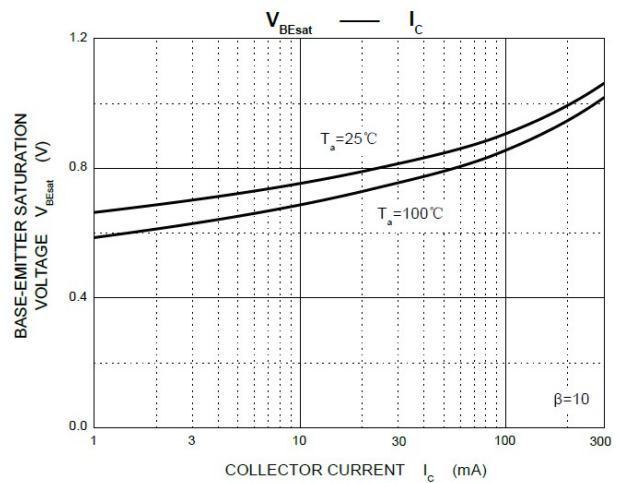
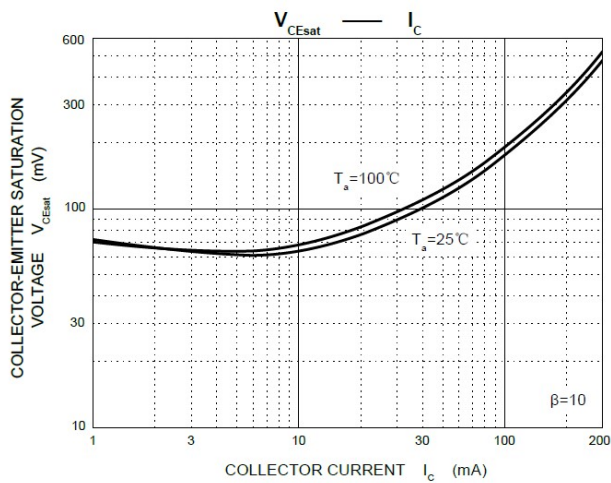
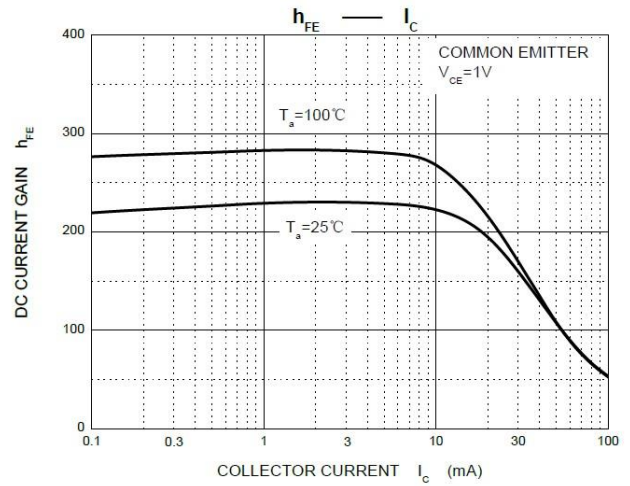
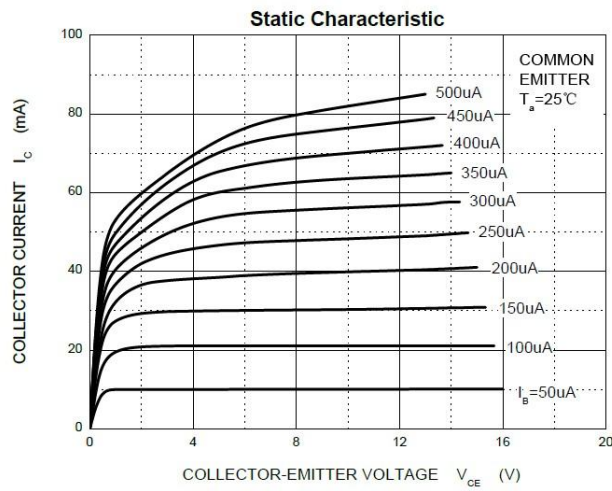
电特性 (TA = 25°C 除非另有规定)

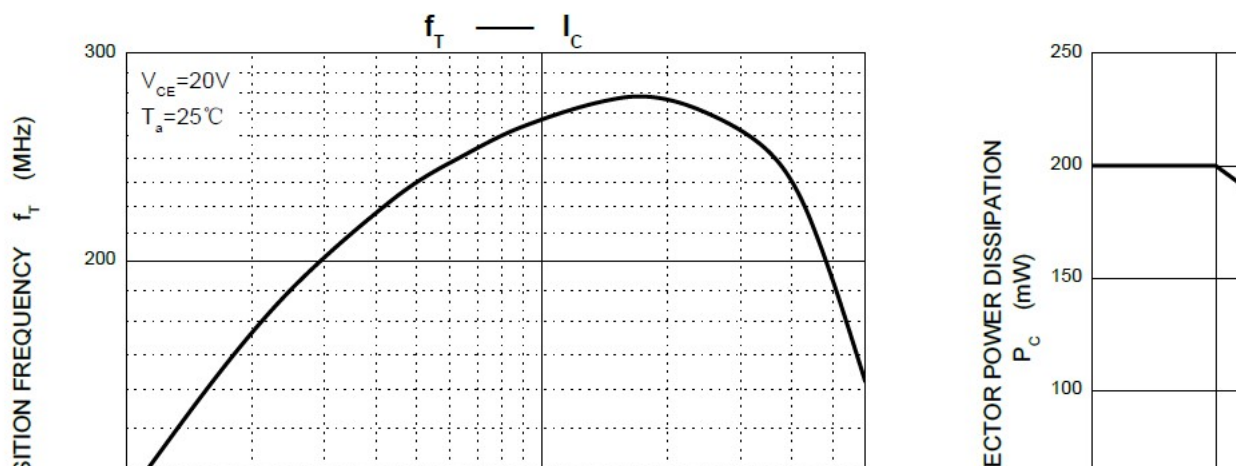
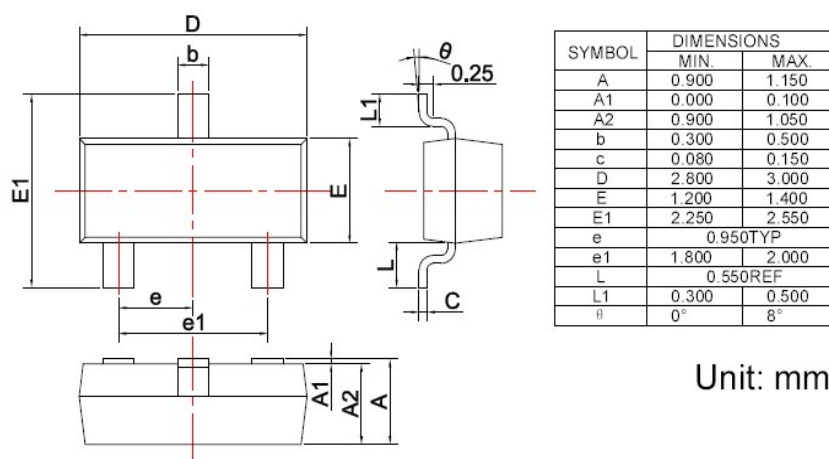
Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

参数 Parameter	符号 Symbols	测试条件 Test Condition	界限 Limits		单位 Unit
			Min	Max	
Collector-base breakdown voltage	V(BR)CBO	IC=10uA, IE=0	60		V
Collector-emitter breakdown voltage	V(BR)CEO	IC=1mA, IB=0	40		V
Emitter-base breakdown voltage	V(BR)EBO	IE=10uA, IC=0	6		V
Collector cut-off current	ICEX	VCE=30V, VEB(off)=3V		50	nA
Collector cut-off current	ICBO	VCE=60V, IE=0		100	nA
Emitter cut-off current	IEBO	VEB=5V, IC=0		100	nA
DC current gain	hFE(1)	VCE=1V, IC=10mA	100	300	
	hFE(2)	VCE=1V, IC=50mA	60		
	hFE(3)	VCE=1V, IC=100mA	30		
Collector-emitter saturation voltage	VCE(sat)	IC=50mA, IB=5mA		0.30	V
Base -emitter saturation voltage	VBE(sat)	IC=50mA, IB=5mA		0.95	V
Transition frequency	f _T	VCE=20V, IC=10mA, f=100MHz	300		MHz
Delay time	t _d	VCC=3V, VBE(off)=-0.5V, IC=10mA, IB1=1mA		35	nS
Rise time	t _r	VCC=3V, VBE(off)=-0.5V, IC=10mA, IB1=1mA		35	nS
Storage time	t _s	VCC=3V, IC=10mA, IB1=IB2=1mA		200	nS
Fall time	t _f	VCC=3V, IC=10mA, IB1=IB2=1mA		50	nS

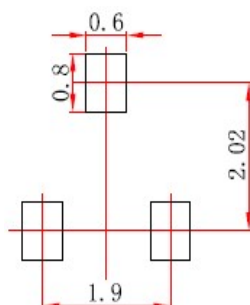
CLASSIFICATION OF hFE(1)

HFE	100-300	
RANK	L	H
RANGE	100-200	200-300

Typical characteristics



SOT-23 PACKAGE OUTLINE Plastic surface mounted package

焊盘设计参考Precautions: PCB Design

Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs



Note:
 1. Controlling dimension: In millimeters.
 2. General tolerance: $\pm 0.05mm$.
 3. The pad layout is for reference purposes only.

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